

SuperMOS – TO-252 -100V BV_{DSS} , $38m\Omega$ $R_{DS(on)}$, P-channel MOSFET

1. Description

The ESE01P30K is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product ESE01P30K is Pb-free.

2. Features

- -100V, $R_{DS(ON)}=38m\Omega$ (Typ.), $V_{GS}=-10V$
 $R_{DS(ON)}=42m\Omega$ (Typ.), $V_{GS}=-4.5V$
- Fast Switching
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

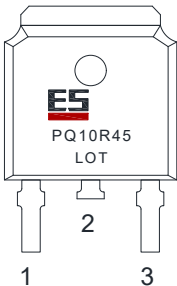
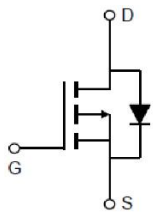
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4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
ESE01P30K	TO-252	PQ10R45/LOT	Halogen free	Tape & Reel	2,500 PCS	UL 94V-0	13 inches

Table-1 Ordering information

5. Pin Configuration and Functions

Pin	Function	Outline	Circuit Diagram
1	Gate	Note b 	
3	Source		
2	Drain		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	-100	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	$T_C=25^{\circ}\text{C}$	I_D	-35	A
	$T_C=100^{\circ}\text{C}$		-22	
Maximum Power Dissipation	$T_C=25^{\circ}\text{C}$	P_D	119	W
Pulsed Drain Current		I_{DM}	-140	A
Avalanche Current, Single Pulsed(L=0.4mH)		I_{AS}	-28	A
Avalanche Energy, Single Pulsed ^a		E_{AS}	156.8	mJ
Operating Junction Temperature		T_J	150	°C
Storage Temperature Range		T_{stg}	-55 to +150	°C

Thermal resistance ratings

Single Operation				
Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance (t≤10s)	$R_{\theta JA}$		55	°C/W
Junction-to-Case Thermal Resistance	$R_{\theta JC}$		1.05	

Note:

a: The test condition is $V_{DD} = -30\text{V}$, $L=0.4\text{mH}$, $I_{AS} = -28\text{A}$.

b: This diagram is only an electrical schematic, and the actual pin size is based on POD.

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter		Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =-250uA	-100			V
Zero Gate Voltage Drain Current	T _J =25℃	I _{DSS}	V _{GS} =0V, V _{DS} =-100V			-1	uA
	T _J =100℃					-100	
Gate-to-source Leakage Current		I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{GS} =V _{DS} , I _D =-250uA	-1.2	-1.7	-2.4	V
Drain-to-source On-resistance		R _{DS(on)}	V _{GS} =-10V, I _D =-20A		38	45	mΩ
			V _{GS} =-4.5V, I _D =-10A		42	58	
Forward Transconductance		g _{FS}	V _{DS} =-10V, I _D =-20A		44		S
Gate Resistance		R _g	f=1MHz		11		Ω
CHARGES, CAPACITANCES AND GATE RESISTANCE							
Input Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =-50V f=1MHz		5000		pF
Output Capacitance		C _{OSS}			151		
Reverse Transfer Capacitance		C _{RSS}			130		
Total Gate Charge		Q _{G(TOT)}	V _{GS} =-10V, V _{DS} =-50V I _D =-20A		115		nC
Gate-to-Source Charge		Q _{GS}			15		
Gate-to-Drain Charge		Q _{GD}			14		
SWITCHING CHARACTERISTICS							
Turn-On Delay Time		t _{d(ON)}	V _{GS} =-10V, V _{DS} =-50V I _D =-20A, R _G =3Ω		14.2		ns
Rise Time		t _r			38.9		
Turn-Off Delay Time		t _{d(OFF)}			65		
Fall Time		t _f			37.5		
BODY DIODE CHARACTERISTICS							
Forward Voltage		V _{SD}	V _{GS} =0V, I _{SD} =-20A			-1.2	V

7. Typical Characteristic

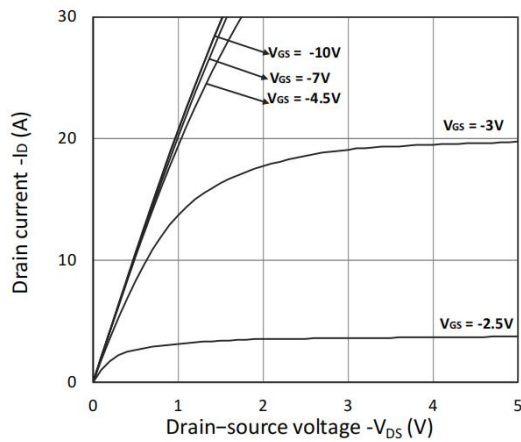


Figure 1. Output Characteristics

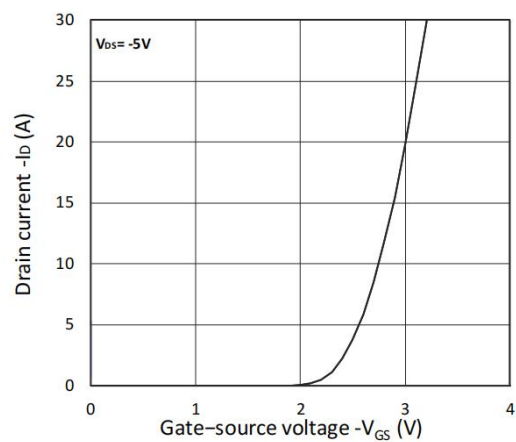


Figure 2. Transfer Characteristics

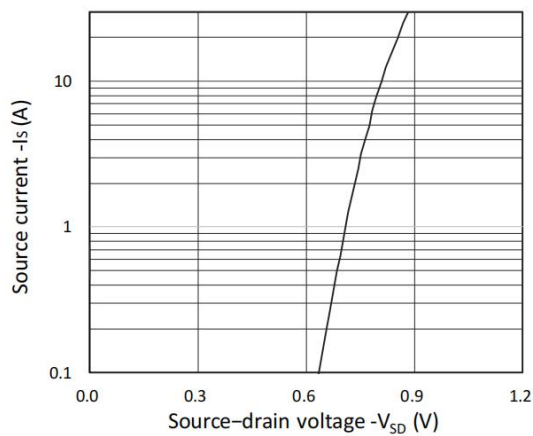


Figure 3. Forward Characteristics of Reverse

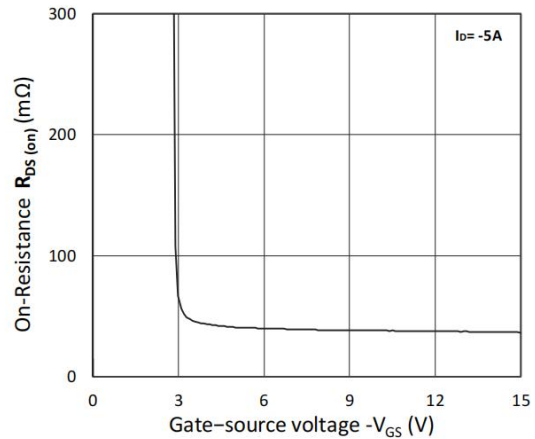
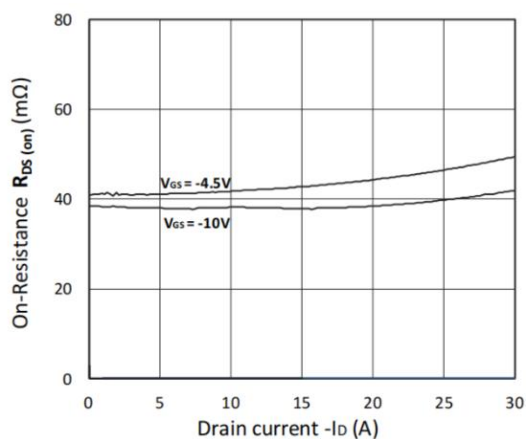
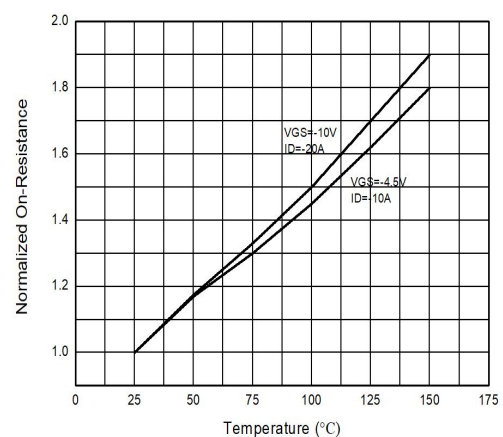
Figure 4. $R_{DS(ON)}$ vs. V_{GS} Figure 5. $R_{DS(ON)}$ vs. I_D 

Figure 6: Normalized On-Resistance vs Temperature

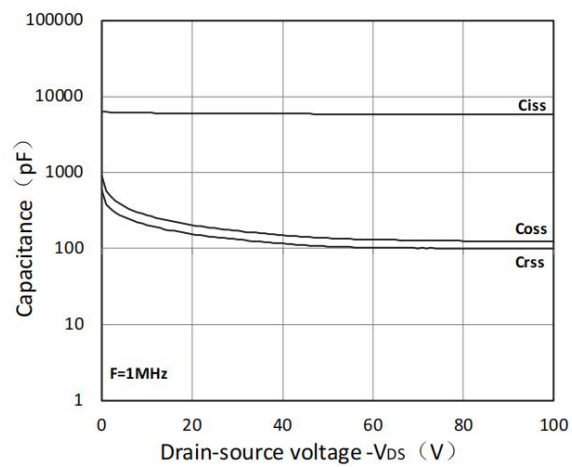


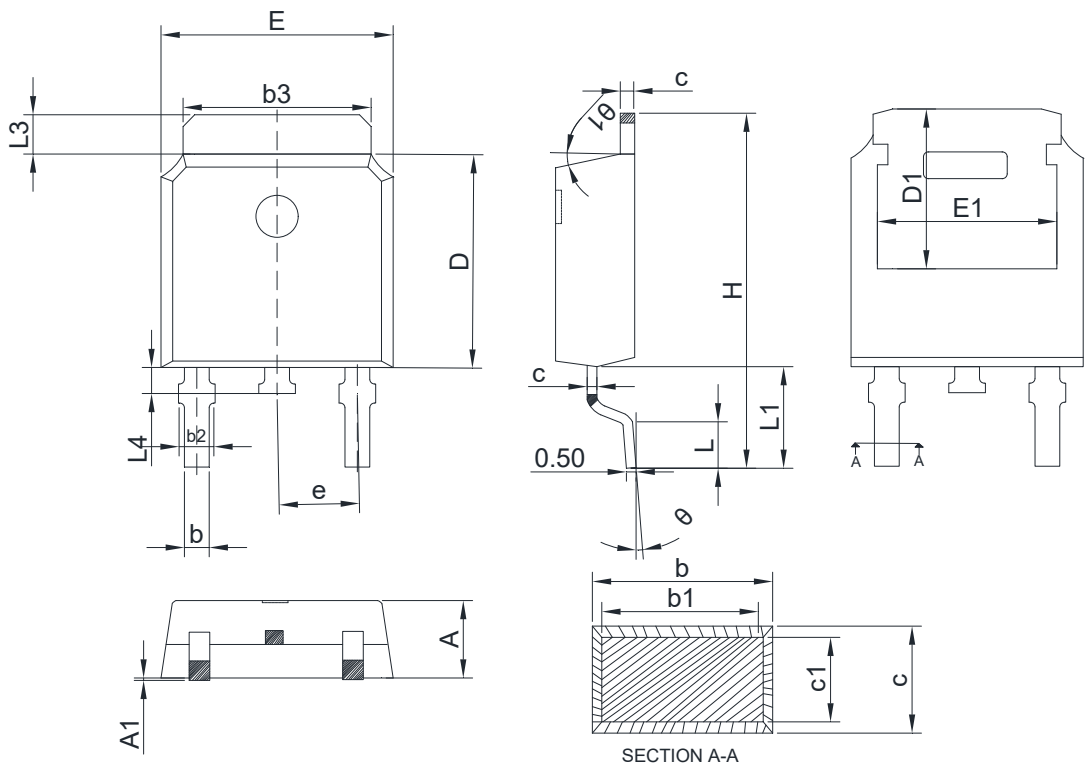
Figure 7. Capacitance Characteristics

ESE01P30K

Rev-1.8

8. Dimension (TO-252)

POD A(Q)

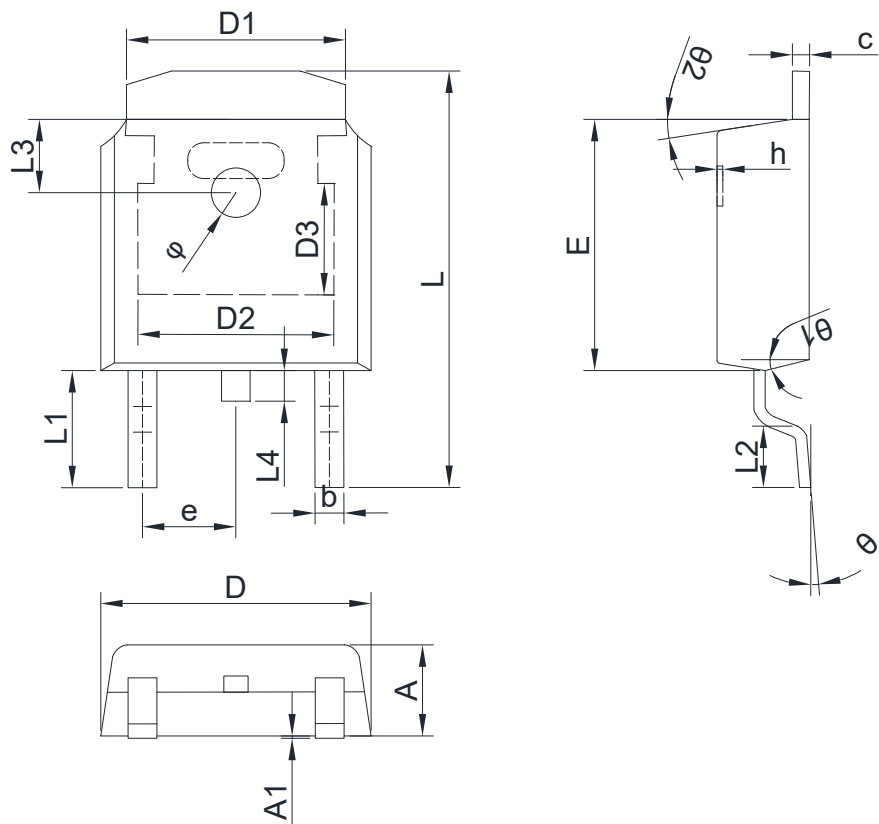


COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER							
SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	2.20	2.30	2.40	D1	5.21	-	-
A1	0.00	-	0.12	E	6.50	6.60	6.70
b	0.65	-	0.89	E1	4.32	-	-
b1	0.64	0.76	0.79	H	9.70	9.95	10.20
b2	0.76	0.86	1.10	L	1.40	1.50	1.60
b3	5.20	5.33	5.46	L1	2.84REF		
c	0.48	-	0.60	e	2.29BSC		
c1	0.47	0.51	0.55	θ	0°	-	10°
D	6.00	6.10	6.20	θ1	0°	-	15°
L3	0.90	-	1.27	L4	0.60	0.80	1.00

ESE01P30K

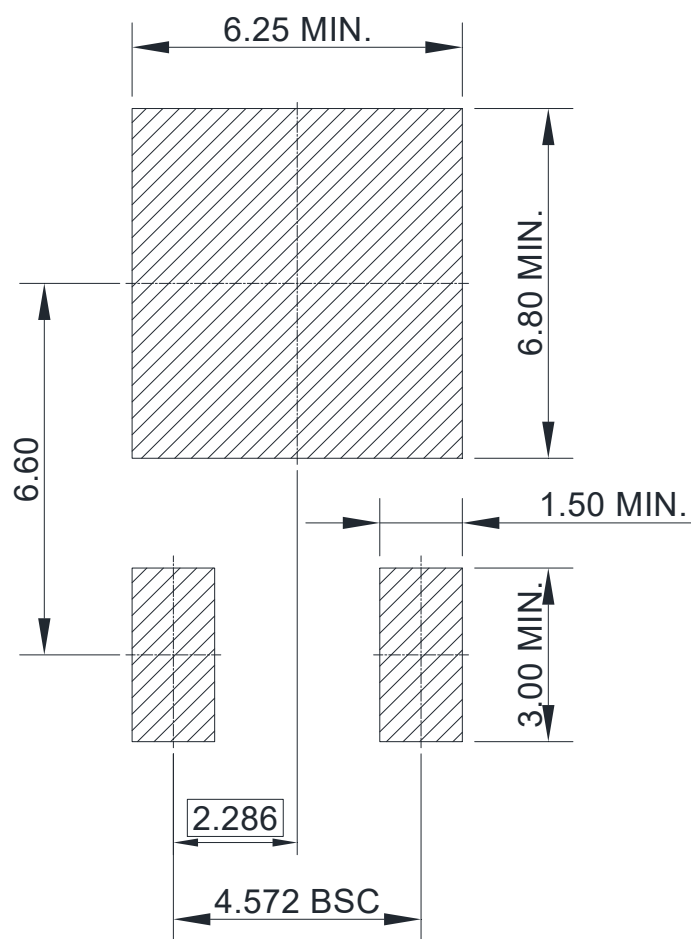
Rev-1.8

POD B(X)



COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER							
SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	2.200	2.300	2.400	h	0.000	0.100	0.200
A1	0.000		0.127	L	9.900	10.100	10.300
b	0.640	0.690	0.740	L1	2.888 REF		
c(电镀后)	0.460	0.520	0.580	L2	1.400	1.550	1.700
D	6.500	6.600	6.700	L3	1.600 REF		
D1	5.334 REF			L4	0.600	0.800	1.000
D2	4.826 REF			φ	1.100	1.200	1.300
D3	3.166 REF			θ	0°		8°
E	6.000	6.100	6.200	θ1	9° TYP		
e	2.286 TYP			θ2	9° TYP		

9. Recommended Soldering Footprint



DIMENSIONS: MILLIMETERS

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